

PSMN075-100MSE

N-channel 100 V 71 m Ω standard level MOSFET in LFPAK33 designed specifically for PoE applications

26 March 2013 Product data sheet

1. General description

New standards and proprietary approaches are enabling the next generation of Power-over-Ethernet (PoE) systems capable of delivering up to 100W to each powered device (PD). Large screen LCD displays, 3G / 4G / Wi-Fi hot-spots and pantilt-zoom CCTV cameras, for example, are placing increased demands on the power sourcing equipment (PSE) in terms of "soft-start" procedures, resilience to short-circuits, thermal management and power density. Part of Nexperia's "NextPower Live" MOSFET portfolio, the PSMN075-100MSE has been designed specifically to compliment the latest PoE controllers, offering both superior linear mode operation and very low RDS(on) in a cost-effective, industry compatible, LFPAK33 package.

2. Features and benefits

- Enhanced forward biased safe operating area for superior linear mode operation
- Low Rdson for low conduction losses
- Ultra reliable LFPAK33 package no glue, no wires, 175°C
- Very low I_{DSS}

3. Applications

- IEEE802.3at and proprietary solutions (type 2)
- Suitable for PoE applications upto 30W
- Use PSMN040-100MSE for higher power requirements

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	100	V
I _D	drain current	T _j = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>		-	-	18	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	65	W
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 25 \text{ °C}; Fig. 12$		-	57	71	mΩ
Dynamic characteristics							
Q_{GD}	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; V_{DS} = 50 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 14; Fig. 15$		-	5.3	-	nC



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{G(tot)}	total gate charge	$V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; V_{DS} = 50 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 14; Fig. 15$	-	16.4	-	nC
Avalanche Ru	ggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 18 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω ; unclamped; Fig. 3	-	-	25	mJ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D
2	S	source		
3	S	source		G-UT4
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN075-100MSE	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN075-100MSE	M75E10

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	100	V
V_{DGR}	drain-gate voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$	-	100	V

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Symbol	Parameter	Conditions	Min	Max	Unit
V _{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 1</u>	-	18	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	-	13	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; Fig. 4	-	74	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	65	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
Source-drai	n diode				
I _S	source current	T _{mb} = 25 °C	-	54	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	74	Α
Avalanche F	Ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_{D} = 18 A; $V_{sup} \le$ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 3	-	25	mJ

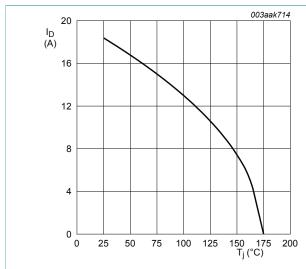


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

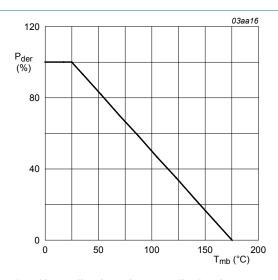


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

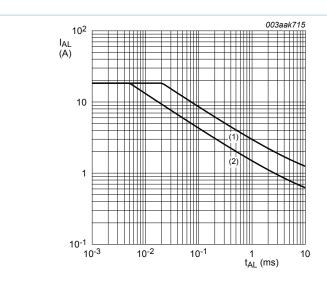


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)
$$T_{j (init)} = 25$$
°C; (2) $T_{j (init)} = 100$ °C

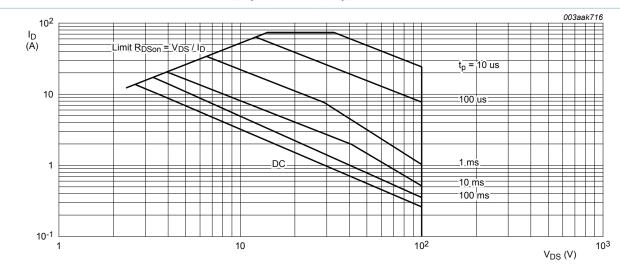


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$$T_{mb} = 25^{\circ}C$$
; I_{DM} is a single pulse

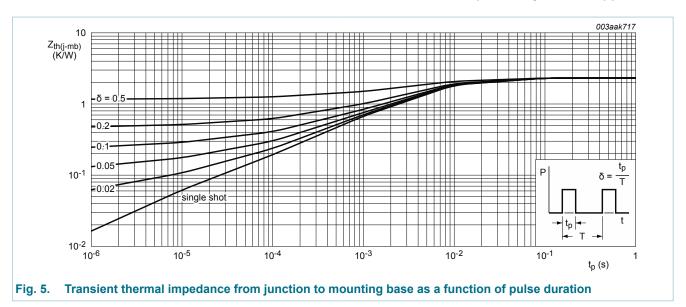
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	2.09	2.32	K/W

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics			'		
V _{(BR)DSS}	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	100	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	90	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 10; Fig. 11	2.3	3.3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 10	1	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 10	-	-	4.6	V
I _{DSS} drain	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.01	1	μA
		V _{DS} = 100 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 5 A; T _j = 25 °C; <u>Fig. 12</u>	-	57	71	mΩ
	resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 100 °C; Fig. 13; Fig. 12	-	-	128	mΩ
		V _{GS} = 10 V; I _D = 5 A; T _j = 175 °C; Fig. 13; Fig. 12	-	-	192	mΩ
R _G	gate resistance	f = 10 MHz	-	1.55	-	Ω

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics			'		
Q _{G(tot)}	total gate charge	$I_D = 5 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 14}}; \underline{\text{Fig. 15}}$	-	16.4	-	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$	-	12.9	-	nC
Q _{GS}	gate-source charge	I _D = 5 A; V _{DS} = 50 V; V _{GS} = 10 V;	-	3.1	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	2.1	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	1	-	nC
Q_{GD}	gate-drain charge	I _D = 5 A; V _{DS} = 50 V; V _{GS} = 10 V; T _j 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.3	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 5 A; V _{DS} = 50 V; T _j = 25 °C; Fig. 14; Fig. 15	-	4.3	-	V
C _{iss}	input capacitance	$V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; Fig. 16$	-	773	-	pF
C _{oss}	output capacitance		-	66	-	pF
C _{rss}	reverse transfer capacitance		-	48	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 50 V; R_{L} = 10 Ω ; V_{GS} = 10 V;	-	5.5	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	5.8	-	ns
t _{d(off)}	turn-off delay time		-	12.4	-	ns
t _f	fall time		-	6.2	-	ns
Source-dra	in diode				1	
V_{SD}	source-drain voltage	I_S = 15 A; V_{GS} = 0 V; T_j = 25 °C; <u>Fig. 17</u>	-	0.89	1.2	V
t _{rr}	reverse recovery time	$I_S = 5 \text{ A}$; $dI_S/dt = -100 \text{ A/}\mu\text{s}$; $V_{GS} = 0 \text{ V}$;	-	35.8	-	ns
Q _r	recovered charge	$V_{DS} = 50 \text{ V}; T_j = 25 \text{ °C}$	-	50.7	-	nC

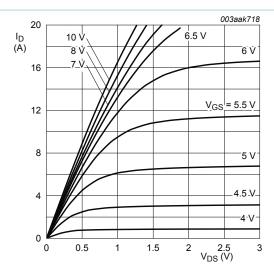


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



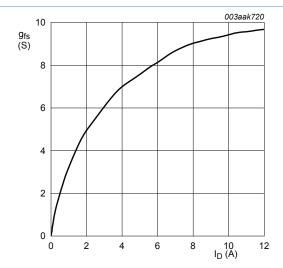


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25^{\circ}C; \ V_{DS} = 10V$$

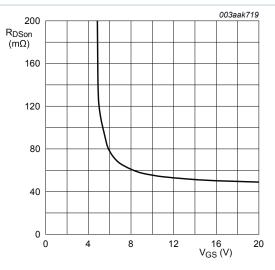


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25$$
°C; $I_D = 5A$

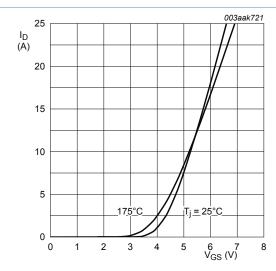


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

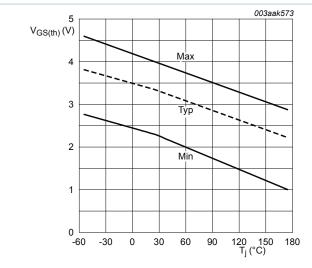


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; \ V_{DS} = V_{GS}$$

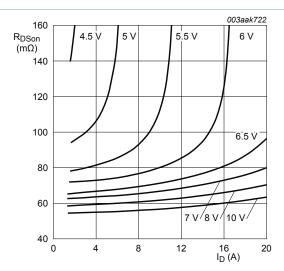


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^{\circ}C$$

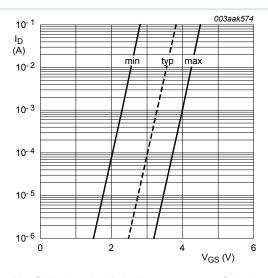


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25 \,^{\circ}C; V_{DS} = 5V$$

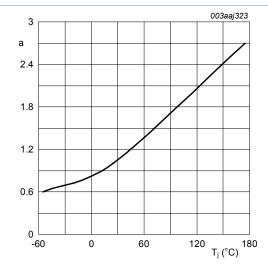


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon} \cos \alpha}$$

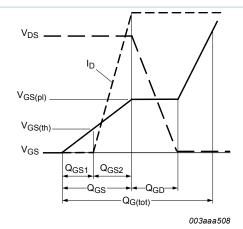


Fig. 14. Gate charge waveform definitions

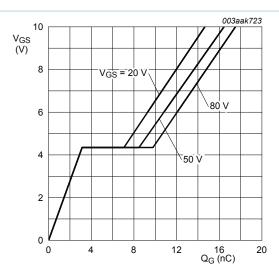


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 5A$$

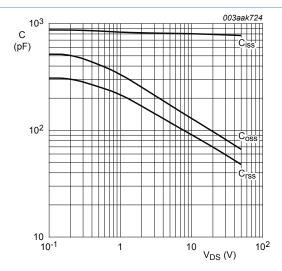
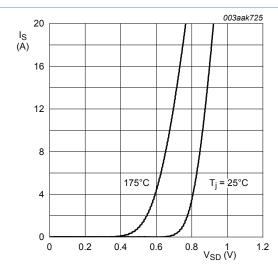


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source current as a function of source-drain as a function of drain-source voltage; typical values

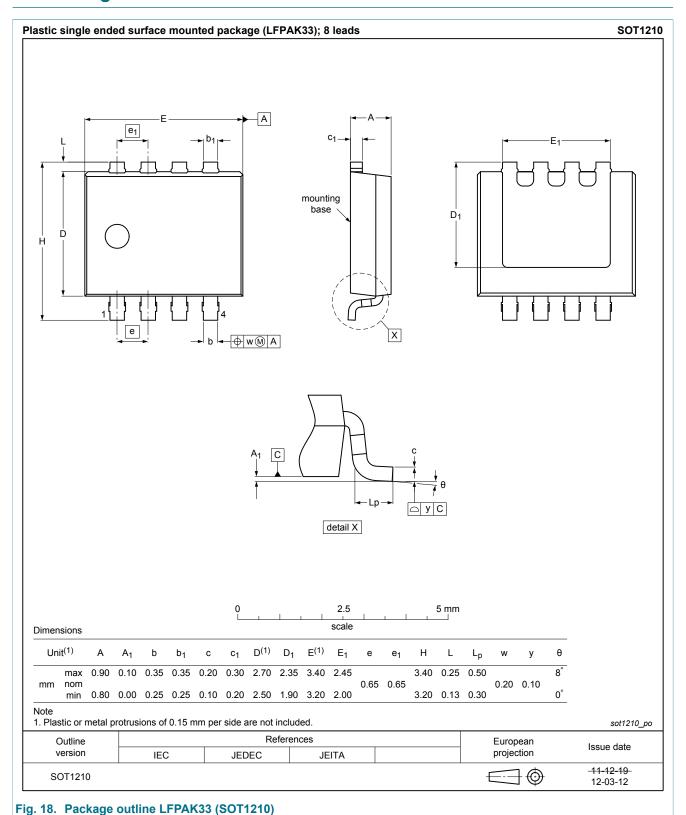
$$V_{GS} = \mathbf{0} V; \ f = \mathbf{1} M Hz$$



voltage; typical values

$$V_{GS} = 0V$$

11. Package outline



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